



Is Now Part of



**ON Semiconductor®**

To learn more about ON Semiconductor, please visit our website at  
[www.onsemi.com](http://www.onsemi.com)

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.



November 2014

# SMBJ5V0(C)A - SMBJ170(C)A 600 Watt Transient Voltage Suppressors

## Features

- Glass-Passivated Junction
- 600 W Peak Pulse Power Capability on 10/1000  $\mu$ s Waveform.
- Excellent Clamping Capability
- Low-Incremental Surge Resistance
- Fast Response Time: Typically Less than 1.0 ps from 0 V to BV minimum for Unidirectional and 5.0 ns for Bidirectional
- Typical  $I_R$  Less than 1.0  $\mu$ A Above 10 V
- UL Certificate #E258596



**SMB/DO-214AA**

Band denotes cathode on unidirectional devices only. No band on bi-directional devices. Bi-directional types have CA suffix where electrical characteristics apply in both directions suitable for bi-directional applications.

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Value	Unit
$P_{PPM}$	Peak Pulse Power Dissipation on 10/1000 $\mu$ s Waveform	600	W
$I_{PPM}$	Peak Pulse Current on 10/1000 $\mu$ s Waveform	See Table	A
$I_{FSM}$	Non-Repetitive Peak Forward Surge Current Superimposed on Rated Load (JEDEC Method) <sup>(1)</sup>	100	A
$T_{STG}$	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
$T_J$	Operating Junction Temperature Range	-55 to 150	$^\circ\text{C}$

### Note:

1. Measured on 8.3 ms single half-sine wave or equivalent square wave: duty cycle = 4 pulses per minute maximum.

SMBJ5V0(C)A - SMBJ170(C)A — 600 Watt Transient Voltage Suppressors

## Electrical Characteristics

Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Uni-Directional Bi-Directional (C) Device	Part Marking <sup>(2)</sup>	Reverse Stand-Off Voltage $V_{RWM}$ (V)	Breakdown Voltage $V_{BR}$ (V)		Test Current $I_T$ (mA)	Clamping Voltage at $I_{PPM}$ $V_C$ (V)	Peak Pulse Current $I_{PPM}$ (A)	Reverse Leakage at $V_{RWM}$ $I_R$ ( $\mu\text{A}$ ) <sup>(3)</sup>
			Min.	Max.				
SMBJ5V0(C)A	KE	5.0	6.40	7.00	10	9.2	65.2	800
SMBJ6V0(C)A	KG	6.0	6.67	7.37	10	10.3	58.3	800
SMBJ6V5(C)A	KK	6.5	7.22	7.98	10	11.2	53.6	500
SMBJ7V0(C)A	KM	7.0	7.78	8.60	10	12.0	50.0	200
SMBJ7V5(C)A	KP	7.5	8.33	9.21	1	12.9	46.5	100
SMBJ8V0(C)A	KR	8.0	8.89	9.83	1	13.6	44.1	50
SMBJ8V5(C)A	KT	8.5	9.44	10.4	1	14.4	41.7	20
SMBJ9V0(C)A	KV	9.0	10.0	11.1	1	15.4	39.0	10
SMBJ10(C)A	KX	10	11.1	12.8	1	17.0	35.3	5
SMBJ11(C)A	KZ	11	12.2	13.5	1	18.2	33.0	5
SMBJ12(C)A	LE	12	13.3	14.7	1	19.9	30.2	5
SMBJ13(C)A	LG	13	14.4	15.9	1	21.5	27.9	5
SMBJ14(C)A	LK	14	15.6	17.2	1	23.2	25.9	5
SMBJ15(C)A	LM	15	16.7	18.5	1	24.4	24.6	5
SMBJ16(C)A	LP	16	17.8	19.7	1	26.0	23.1	5
SMBJ17(C)A	LR	17	18.9	20.9	1	27.6	21.7	5
SMBJ18(C)A	LT	18	20.0	22.1	1	29.2	20.5	5
SMBJ20(C)A	LV	20	22.2	24.5	1	32.4	18.5	5
SMBJ22(C)A	LX	22	24.4	26.9	1	35.5	16.9	5
SMBJ24(C)A	LZ	24	26.7	29.5	1	38.9	15.4	5
SMBJ26(C)A	ME	26	28.9	31.9	1	42.1	14.3	5
SMBJ28(C)A	MG	28	31.1	34.4	1	45.4	13.2	5
SMBJ30(C)A	MK	30	33.3	36.8	1	48.4	12.4	5
SMBJ33(C)A	MM	33	36.7	40.6	1	53.3	11.3	5
SMBJ36(C)A	MP	36	40.0	44.2	1	58.1	10.3	5
SMBJ40(C)A	MR	40	44.4	49.1	1	64.5	9.3	5
SMBJ43(C)A	MT	43	47.8	52.8	1	69.4	8.6	5
SMBJ45(C)A	MV	45	50.0	55.3	1	72.7	8.3	5
SMBJ48(C)A	MX	48	53.3	58.9	1	77.4	7.8	5
SMBJ51(C)A	MZ	51	56.7	62.7	1	82.4	7.3	5
SMBJ54(C)A	NE	54	60.0	66.3	1	87.1	6.9	5
SMBJ58(C)A	NG	58	64.4	71.2	1	93.6	6.4	5
SMBJ60(C)A	NK	60	66.7	73.7	1	96.8	6.2	5
SMBJ64(C)A	NM	64	71.1	78.6	1	103.0	5.8	5
SMBJ70(C)A	NP	70	77.8	86.0	1	113.0	5.3	5
SMBJ75(C)A	NR	75	83.3	92.1	1	121.0	5.0	5
SMBJ78(C)A	NT	78	86.7	95.8	1	126.0	4.8	5

### Notes:

2. Color band denotes cathode on unidirectional devices only. No color band on bidirectional devices.
3. For bidirectional parts with  $V_{RWM} < 10$  V, the  $I_R$  max limit is doubled.

**Electrical Characteristics** (Continued)Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Uni-Directional Bi-Directional (C) Device	Part Marking <sup>(2)</sup>	Reverse Stand-Off Voltage $V_{RWM}$ (V)	Breakdown Voltage $V_{BR}$ (V)		Test Current $I_T$ (mA)	Clamping Voltage at $I_{PPM}$ $V_C$ (V)	Peak Pulse Current $I_{PPM}$ (A)	Reverse Leakage at $V_{RWM}$ $I_R$ ( $\mu\text{A}$ ) <sup>(3)</sup>
			Min.	Max.				
SMBJ85(C)A	NV	85	94.4	104.0	1	137.0	4.4	5
SMBJ90(C)A	NX	90	100.0	111.0	1	146.0	4.1	5
SMBJ100(C)A	NZ	100	111.0	123.0	1	162.0	3.7	5
SMBJ110(C)A	PE	110	122.0	135.0	1	177.0	3.4	5
SMBJ120(C)A	PG	120	133.0	147.0	1	193.0	3.1	5
SMBJ130(C)A	PK	130	144.0	159.0	1	209.0	2.9	5
SMBJ150(C)A	PM	150	167.0	185.0	1	243.0	2.5	5
SMBJ160(C)A	PP	160	178.0	197.0	1	259.0	2.3	5
SMBJ170(C)A	PR	170	189.0	209.0	1	275.0	2.2	5

**Notes:**

- Color band denotes cathode on unidirectional devices only. No color band on bidirectional devices.
- For bidirectional parts with  $V_{RWM} < 10$  V, the  $I_R$  max limit is doubled.

## Typical Performance Characteristics



Figure 1. Peak Pulse Power Rating Curve



Figure 2. Pulse Derating Curve



Figure 3. Pulse Waveform



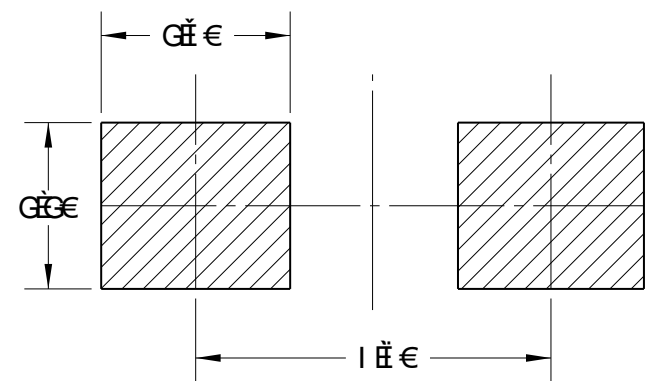
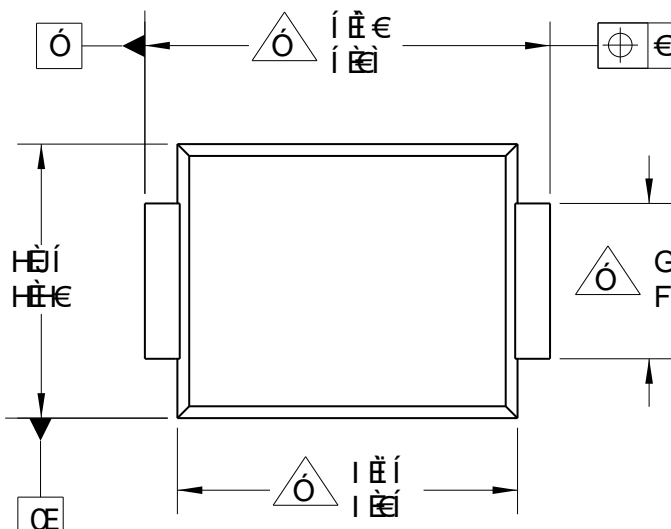
Figure 4. Junction Capacitance



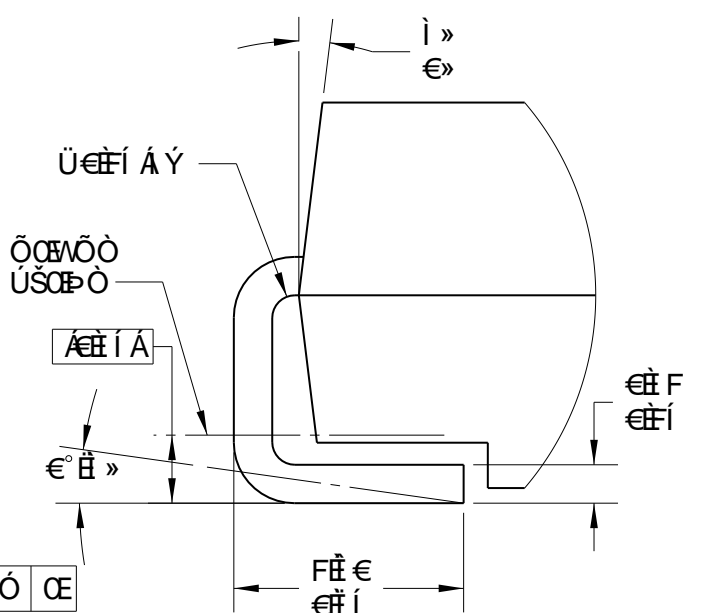
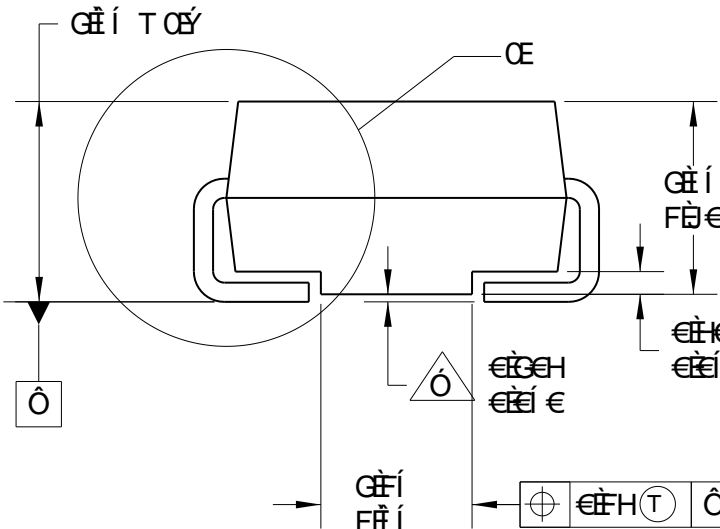
Figure 5. Non-Repetitive Surge Current

VP:SHOBY Φ ΟΑΒΡΡΑΟΔΙΙΟΟΥΥΑΙΟΚΩΒΟΡΦΟΑΜΟΤ ΣΕΡΟΝΟΝΥΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟ  
 VP:OOUΦΑΡΠΕΣΣΟΑΤ ΔΕΔΑΥΡΟΑΡΦΕΡΕΑΒΙΟΟΟΟΦΟΑΚΑΙΔΑΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟΤ ΔΙΟΟ  
 VU:ΑΒΕΡΦΟΦΑΜΟΤ ΣΕΡΟΝΟΝΥΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟΔΑΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟΤ ΔΙΟΟ  
 Y ΦΡΑΓΗΡΑΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟΔΑΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟΤ ΣΕΡΟΝΟΝΥΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟ  
 ΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟΔΑΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟΔΑΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟΤ ΣΕΡΟΝΟΝΥΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟ  
 ΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟΔΑΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟΔΑΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟΤ ΣΕΡΟΝΟΝΥΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟ  
 U:ΑΡ:SHOBY Φ ΟΑΒΡΡΑΟΔΙΙΟΟΥΥΑΙΟΚΩΒΟΡΦΟΑΜΟΤ ΣΕΡΟΝΟΝΥΙΟΔΙΙΟΟΥΟΒΕΡΦΕΡΒΗΜΑΙΟ

ΥΟΧΩΠΒ			
ΡΟΪ	ΟΟΥΟΪΩΠΩΠ	ΟΕ/Ο	ΟΪΠΩΪΩ
F	ΥΟΣΟΑΪΟΑΥ/ΟΟ	FJT ΟΪΓΕΕ	ΥΟΣΟΑΪΩΪΩ



ΣΟΦ ΟΑΪΩΕ/ΝΟΥΡΑΪΟΟΟΥΤ Τ ΟΡΟΕ/ΩΠ



ΟΟΝΟΕΣΑΪΑ  
 ΥΟΣΟΑΪΩΕ/Μ

ΡΥΝΟΪΚ  
 ΑΚΕΪΟΪ ΟΟΥΝΑ ΡΟΪΟΑΡΥΝΟΪΟΪΠΩΪΩΪΩΤ ΪΑΪΑ  
 ΡΟΪΟΪΟΪΩΓΦ ΑΚΕΪΩΕ/ΩΠΑΪΕ  
 Δ ΟΟΥΑΡΥΝΟΪΩΤ ΪΣΥΑΡΟΪΟΪΩΝΟΑΚΕΪΩΕ  
 ΑΚΕΪΩΕΣΑΪΩ ΟΡΥΩΠΩΪΑΪΩΑΪΩΤ ΣΣΟ ΟΝΟΪΩΕ  
 ΑΚΕΪΩΕ ΟΡΥΩΠΩΪΑΪΩΑΪΩΪΩΣΪΩΪΩΑΪΩΪΩΪΩΪΩΪΩ  
 ΑΪ ΪΣΟΑΪΩΕΡΑΪΩ ΟΑΪΩΑΪΩΕΪΑΪΩΪΩΪΩΪΩΪΩΪΩ  
 ΑΚΕΪΩΕ ΟΡΥΩΠΩΪΑΪΩ ΟΑΪΩΪΩΪΩΕ ΟΑΪΩΪΩΪΩΪΩ  
 ΪΦ Ϊ Ϊ Ϊ Ϊ Ϊ  
 ΑΚΕΪΩΕ ΟΑΪΩΕ/ΝΟΥΡΑΪΩΝΟΪΩΤ Ϊ Η Ϊ Γ Ε Ϊ Ε  
 ΑΚΕΪΩΕΪΩΕ Φ ΟΑΪΩΕ/ΩΠ ΟΚΩΪΩΓΦ ΑΚΕΪΩΕ

ΑΪΪΪΪΪΪΪΪ	ΟΕ/Ο		ΓΣΟΕΪΩΤ ΟΑΡΟΪΟΪΟ ΟΪΩΓΦ ΑΚΕΪΩΕ/ΩΠΑΪΕ											
ΟΪΩΪΩ ΪΚ ΟΟΥΪΑΤ ΑΪΣΪ	FJT ΟΪΓΕΕ													
ΟΡΟΪΟΪΚ ΥΟΑΪΩ														
ΑΪΪΪΪΪΪΪΪ ΑΪΩΑΪΩ														
ΑΪΪΪΪΪΪΪΪ ΡΥΪ ΑΪΩΑΪΩ														
ΥΟΥΡΟΪΩΠ		<table border="1"> <tr> <th>ΥΟΪΩ</th> <th>ΥΪΩ</th> <th>ΟΪΩΪΩ ΦΟΪΩΪΩΤ ΟΪΩ</th> <th>ΥΟΪΚ</th> </tr> <tr> <td>FJT</td> <td>ΪΩΕ</td> <td>T SV ΕΪΩΓΦ ΑΚΕΪΩΕ</td> <td>F</td> </tr> <tr> <td colspan="3">ΑΪΩΤ ΟΪΩΤΚ ΪΩΕ</td> <td>ΪΠΟΪΩΚ ΑΪΩΕ</td> </tr> </table>	ΥΟΪΩ	ΥΪΩ	ΟΪΩΪΩ ΦΟΪΩΪΩΤ ΟΪΩ	ΥΟΪΚ	FJT	ΪΩΕ	T SV ΕΪΩΓΦ ΑΚΕΪΩΕ	F	ΑΪΩΤ ΟΪΩΤΚ ΪΩΕ			ΪΠΟΪΩΚ ΑΪΩΕ
ΥΟΪΩ	ΥΪΩ	ΟΪΩΪΩ ΦΟΪΩΪΩΤ ΟΪΩ	ΥΟΪΚ											
FJT	ΪΩΕ	T SV ΕΪΩΓΦ ΑΚΕΪΩΕ	F											
ΑΪΩΤ ΟΪΩΤΚ ΪΩΕ			ΪΠΟΪΩΚ ΑΪΩΕ											

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor  
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA  
**Phone:** 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
**Fax:** 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
**Email:** [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

**N. American Technical Support:** 800-282-9855 Toll Free  
USA/Canada  
**Europe, Middle East and Africa Technical Support:**  
Phone: 421 33 790 2910  
**Japan Customer Focus Center**  
Phone: 81-3-5817-1050

**ON Semiconductor Website:** [www.onsemi.com](http://www.onsemi.com)  
**Order Literature:** <http://www.onsemi.com/orderlit>  
For additional information, please contact your local  
Sales Representative